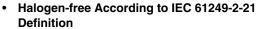


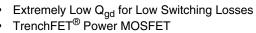


N-Channel 30 V (D-S) Fast Switching MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A)			
30	0.00825 at V _{GS} = 10 V	15			
	0.00975 at V _{GS} = 4.5 V	13			

FEATURES



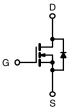


New Low Thermal Resistance PowerPAK® Package with Low 1.07 mm Profile

- 100 % R_q Tested
- Compliant to RoHS Directive 2002/95/EC

APPLICATIONS

- · High-Side DC/DC Conversion
 - Notebook
 - Server



N-Channel MOSFET

PowerPAK SO-8
6.15 mm 5.15 mm 4 6.15 mm
Bottom View

Ordering Information: Si7342DP-T1-E3 (Lead (Pb)-free)

Si7342DP-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C, unless otherwise noted)						
Parameter		Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		V_{DS}	30		V	
Gate-Source Voltage		V_{GS}	± 12			
Continuous Drain Current /T = 150 °C\8	T _A = 25 °C	I _D	15	9	А	
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C		12	7		
Pulsed Drain Current		I _{DM}	± 60		A	
Continuous Source Current (Diode Conduction) ^a		I _S	4.1	1.5		
Maximum Dawar Dissinations	T _A = 25 °C	P _D	5	1.8	W	
Maximum Power Dissipation ^a	T _A = 70 °C		3.2	1.1		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C	
Soldering Recommendations (Peak Temperature)b, c		-	260			

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum Junation to Ambient (MOCFFT)	t ≤ 10 s	- R _{thJA}	20	25	°C/W
Maximum Junction-to-Ambient (MOSFET) ^a	Steady State		53	70	
Maximum Junction-to-Case (Drain)	Steady State	R _{thJC}	2.1	3.2	

- a. Surface mounted on 1" x 1" FR4 board.
- b. See solder profile (www.vishay.com/ppg?73257). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- c. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.

Vishay Siliconix



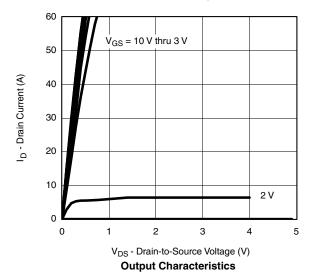
Parameter	Symbol	Test Conditions Min.		Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	0.6		1.8	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 12 \text{ V}$			± 100	nA	
Zero Gate Voltage Drain Current		V _{DS} = 30 V, V _{GS} = 0 V			1		
	I _{DSS}	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 70 ^{\circ}\text{C}$			10	μΑ	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	40			Α	
Drain-Source On-State Resistance ^a	В	V _{GS} = 10 V, I _D = 15 A		0.0066	0.00825	0	
	R _{DS(on)}	V _{GS} = 4.5 V, I _D = 13 A		0.0077	0.00975	Ω	
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 15 A		65		S	
Diode Forward Voltage ^a	V_{SD}	I _S = 2.9 A, V _{GS} = 0 V		0.73	1.1	V	
Dynamic ^b							
Input Capacitance	C _{iss}			1900		pF	
Output Capacitance	C _{oss}	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		530			
Reverse Transfer Capacitance	C _{rss}			120			
Total Gate Charge	Q_g			12.5	19		
Gate-Source Charge	Q_{gs}	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 15 \text{ A}$		3.9		nC	
Gate-Drain Charge	Q_{gd}			2.1			
Gate Resistance	R_{g}		0.8	1.2	1.8	Ω	
Turn-On Delay Time	t _{d(on)}			13	20		
Rise Time	t _r	V_{DD} = 15 V, R_L = 15 Ω		8	13		
Turn-Off Delay Time	t _{d(off)}	$I_D\cong$ 1 A, V_{GEN} = 10 V, R_G = 6 Ω		48	75	ns	
Fall Time	t _f			13	20		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 2.9 A, dI/dt = 100 A/μs		36	55		

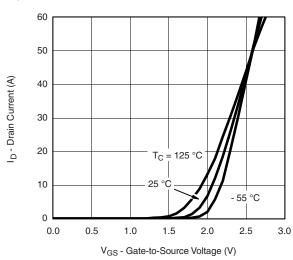
Notes:

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

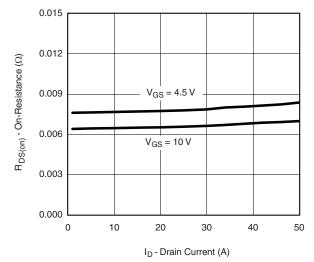




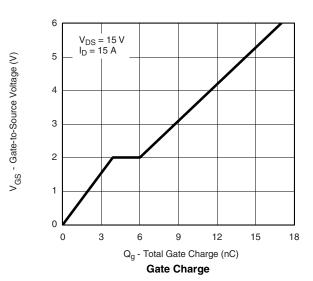


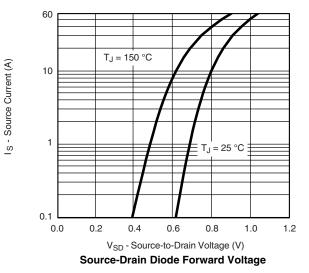


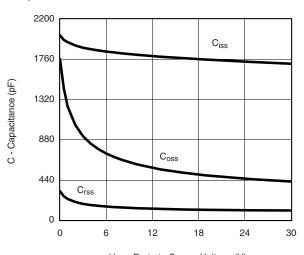
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



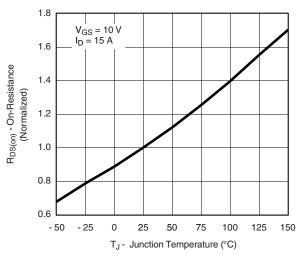
On-Resistance vs. Drain Current



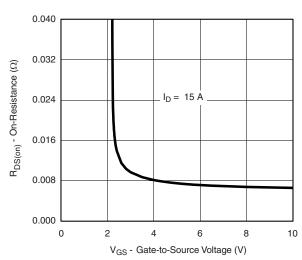




V_{DS} - Drain-to-Source Voltage (V) **Capacitance**



On-Resistance vs. Junction Temperature

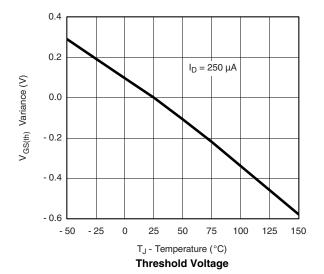


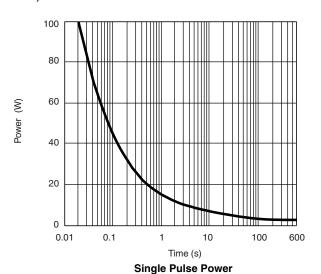
On-Resistance vs. Gate-to-Source Voltage

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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)





Limited by $R_{DS(on)}$;

10

10

10

10 ms

10 ms

100 ms

100 ms

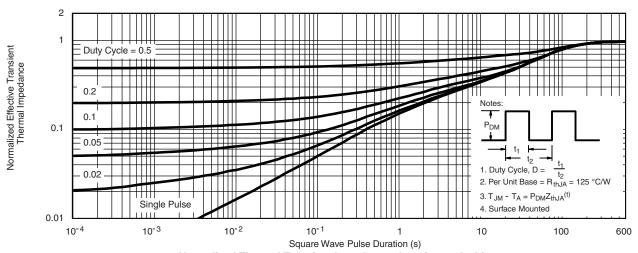
100 ms

100 ms

100 ms

100 ms

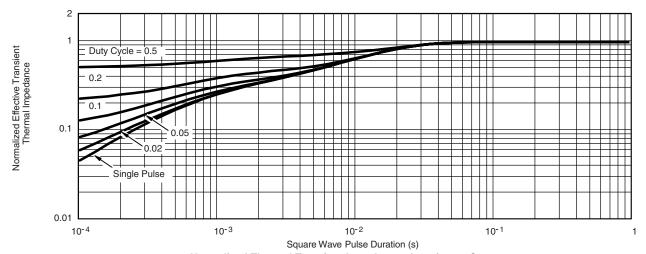
$$\begin{split} &V_{DS}\text{ - Drain-to-Source Voltage (V)}\\ ^*V_{GS}\text{ > minimum }V_{GS}\text{ at which }R_{DS(on)}\text{ is specified}\\ &\textbf{Safe Operating Area, Junction-to-Case} \end{split}$$



Normalized Thermal Transient Impedance, Junction-to-Ambient



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

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